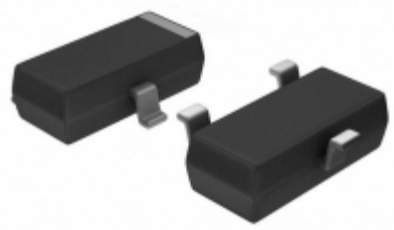









	<h2 style="color: red;">FJV3113RMTF</h2>	
	Hersteller-Teilenummer:	FJV3113RMTF
	Hersteller / Marke:	AMI Semiconductor / ON Semiconductor
	Teil der Beschreibung:	TRANS PREBIAS NPN 200MW SOT23-3
	Datenblätter:	1.FJV3113RMTF.pdf 2.FJV3113RMTF.pdf
	RoHS Status:	Bleifrei / RoHS-konform
Lagerzustand:	New original, 51980 pcs Stock Available.	
Liefern von:	Hong Kong	
Versandweg:	DHL/Fedex/TNT/UPS/EMS	
Image may be representation. See specs for product details.		

Spezifikationen

Teilenummer	FJV3113RMTF
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	TRANS PREBIAS NPN 200MW SOT23-3
Kategorie	Diskrete Halbleiterprodukte > Transistoren-Bipolar
Teilstatus	51980 pcs Stock
Hersteller Standard Vorlaufzeit	2 Weeks
detaillierte Beschreibung	Pre-Biased Bipolar Transistor (BJT) NPN - Pre-Biased
Serie	-
Befestigungsart	Surface Mount
Leistung - max	200mW
Verpackung / Gehäuse	TO-236-3, SC-59, SOT-23-3
Supplier Device-Gehäuse	SOT-23-3 (TO-236)
Transistor-Typ	NPN - Pre-Biased
Strom - Kollektor (Ic) (max)	100mA
Spannung - Kollektor-Emitter-Durchbruch (max)	50V
VCE Sättigung (Max) @ Ib, Ic	300mV @ 500µA, 10mA
Strom - Collector Cutoff (Max)	100nA (ICBO)
DC Stromgewinn (HFE) (Min) @ Ic, VCE	68 @ 5mA, 5V
Frequenz - Übergang	250MHz
Verpackung	Original-Reel®
Basisteilenummer	FJV3113
Widerstand - Basis (R1)	2.2 kOhms
Widerstand - Emitterbasis (R2)	47 kOhms
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	FJV3113RMTFDKR

FJV3113RMTF ist neu im Original, Suche FJV3113RMTF Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FJV3113RMTF AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FJV3113RMTF: Info@Y-IC.com

Sie können auch interessiert sein:

 FJV3115RMTF Fairchild/ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3	 FJV3111RMTF Fairchild/ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3	 FJV4101RMTF Fairchild/ON Semiconductor TRANS PREBIAS PNP 200MW SOT23-3	 FJV3114RMTF Fairchild/ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3
 FJV3112RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3	 FJV3114RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3	 FJV3113RMTF Fairchild/ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3	 FJV3115RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3

heiße Teile

Mehr

⊕ FJV3101RMTF	↔ FJV3101RMTF	⇒ FJV3102RMTF	D FJV3102RMTF	↗ FJV3103RMTF
⊕ FJV3103RMTF	⊕ FJV3104RMTF	D FJV3104RMTF	↗ FJV3105RMTF	↗ FJV3105RMTF
⊕ FJV3106RMTF	⊕ FJV3106RMTF	⊕ FJV3107RMTF	↔ FJV3107RMTF	↗ FJV3108RMTF
D FJV3108RMTF	⊕ FJV3109R	⊕ FJV3109RMTF	⊕ FJV3109RMTF	↗ FJV3110RMTF
⇒ FJV3110RMTF	↔ FJV3111RMTF	⊕ FJV3111RMTF	⊕ FJV3112RMTF	↗ FJV3112RMTF
↔ FJV3113RMTF	⇒ FJV3114RMTF	D FJV3114RMTF	⊕ FJV3115RMTF	⊕ FJV3115RMTF
⊕ FJV4101RMTF	D FJV4101RMTF	⇒ FJV4102RLIMTF	↔ FJV4102RMTF	↗ FJV4102RMTF
⊕ FJV4103RMTF	⊕ FJV4103RMTF	↔ FJV4104RMTF	⇒ FJV4104RMTF	↗ FJV4105RMTF
⊕ FJV4105RMTF	⊕ FJV4106RMTF	⊕ FJV4106RMTF	D FJV4107RMTF	↗ FJV4107RMTF
↔ FJV4108RMTF	⊕ FJV4108RMTF	⊕ FJV4109RMTF	⊕ FJV4109RMTF	↗ FJV4110RMTF

Contact us: Info@Y-IC.com

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